


	<h2 style="color: red;">SIA431DJ-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIA431DJ-T1-GE3</p> <hr/> <p>Hersteller / Marke: Vishay / Siliconix</p> <hr/> <p>Teil der Beschreibung: MOSFET P-CH 20V 12A PPAK SC70-6</p> <hr/> <p>Datenblätter:  SIA431DJ-T1-GE3.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 79986 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA431DJ-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 12A PPAK SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	79986 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SC-70-6
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Single
Verlustleistung (max)	3.5W (Ta), 19W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Tc)
Rds On (Max) @ Id, Vgs	25 mOhm @ 6.5A, 4.5V
VGS (th) (Max) @ Id	850mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	1700pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs (Max)	±8V
Verpackung	Original-Reel®



















































SIA431DJ-T1-GE3 ist neu im Original, Suche SIA431DJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA431DJ-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIA431DJ-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIA430DJT-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 12A SC70-6</p>	 <p>SIA431DJ-T1-GE3 Vishay / Spectrol MOSFET P-CH 20V 12A PPAK SC70-6</p>	 <p>SIA430DJT-T1-GE3 VISHAY VISHAY QFN-6</p>	 <p>SIA431DJ-T1 VISHAY SIA431DJ-T1 VISHAY</p>
 <p>SIA433EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 12A SC-70-6</p>	 <p>SIA432DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 12A SC70-6</p>	 <p>SIA430DJT-T1-E3 VISHAY VISHAY QFN-6</p>	 <p>SIA433EDJ VISHAY SIA433EDJ VISHAY</p>

heiße Teile

Mehr

 SIA413DJ-T4-GE3	 SIA414DJ-T1-GE3	 SIA414DJ-T1-GE3	 SIA415DJ-T1-GE3	 SIA415DJ-T1-GE3
 SIA417DJ-T1-GE3	 SIA417DJ-T1-GE3	 SIA419DJ	 SIA419DJ-T1-GE3	 SIA419DJ-T1-GE3
 SIA421DJ-T1-GE3	 SIA421DJ-T1-GE3	 SIA425EDJ-T1-GE3	 SIA425EDJ-T1-GE3	 SIA426DJ-T1-GE3
 SIA426DJ-T1-GE3	 SIA427DJ-T1-GE3	 SIA427DJ-T1-GE3	 SIA429DJT-T1-GE3	 SIA429DJT-T1-GE3
 SIA430DJ-T1-GE3	 SIA430DJ-T1-GE3	 SIA431DJ	 SIA431DJ-T1	 SIA431DJ-T1-GE3
 SIA432DJ-T1-GE3	 SIA432DJ-T1-GE3	 SIA433EDJ	 SIA433EDJ-T1-GE3	 SIA433EDJ-T1-GE3
 SIA436DJ-T1-GE3	 SIA436DJ-T1-GE3	 SIA443DJ-T1-GE3	 SIA443DJ-T1-GE3	 SIA444DJT-T1-GE3
 SIA444DJT-T1-GE3	 SIA445EDJ-T1-GE3	 SIA445EDJ-T1-GE3	 SIA447DJ-T1-GE3	 SIA447DJ-T1-GE3
 SIA448DJ-T1-GE3	 SIA448DJ-T1-GE3	 SIA449DJ-GE3	 SIA450DJ-T1-GE3	 SIA450DJ-T1-GE3
 SIA4528-100K	 SIA4528-330K	 SIA4528-470K	 SIA453EDJ-T1-GE3	 SIA453EDJ-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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